

# BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu PC4570$

## **DUAL ULTRA LOW-NOISE, WIDEBAND, OPERATIONAL AMPLIFIER**

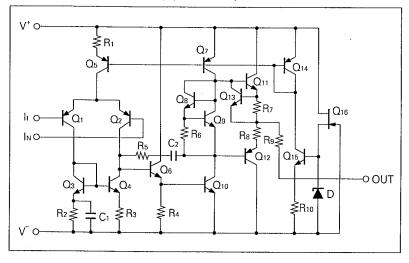
#### **DESCRIPTION**

The  $\mu$ PC4570 is an ultra low-noise, wideband high slew-rate, dual operational amplifier. Input equivalent noise is three times better than the conventional 4558 type op-amps. The gain bandwidth products and the slew-rate are seven times better than 4558. In spite of fast AC performance, the  $\mu$ PC4570 is extremely stable under voltage-follower circuit conditions. Supply current is also improved compared with conventional wideband op-amps. The  $\mu$ PC4570 is an excellent choice for pre-amplifiers and active filters in audio, instrumentation, and communication circuits.

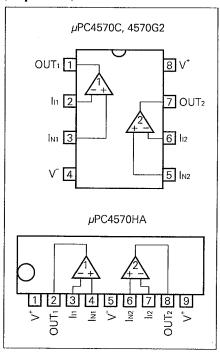
#### **FEATURES**

- Ultra low noise : en = 4.5 nV/√Hz
- High slew rate: 7 V/μs
- High gain bandwidth product:
  GBW = 15 MHz at 100 kHz
- Internal frequency compensation

#### **EQUIVALENT CIRCUIT (1/2 Circuit)**



# CONNECTION DIAGRAM (Top View)



#### ORDERING INFORMATION

PART NUMBER	PACKAGE	QUALITY GRADE
μPC4570C	8 PIN PLASTIC DIP (300 mil)	Standard
μPC4570G2	8 PIN PLASTIC SOP (225 mil)	Standard
μPC4570HA	9 PIN SLIM SIP	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

PARA	METER	SYMBOL	μPC4570	UNIT
Voltage between V⁺ and V⁻ (Note1)		V+ -V-	−0.3 to +36	V
Differential Input Vo	oltage	V <sub>ID</sub>	±30	V
Input Voltage	(Note 2)	Vı	V <sup>-</sup> -0.3 to V <sup>+</sup> +0.3	V
Output Voltage	(Note 3)	Vo	V⁻ −0.3 to V⁺ +0.3	V
	C Package (Note 4)		350	mW
Power Dissipation	G2 Package (Note 5)	Pτ	440	mW
	HA Package (Note 4)		350	mW
∪Output Short Circuit	t Duration (Note 6)		10	sec
Operating Temperat	ture Range	Topt	-20 to +80	°C
Storage Temperatur	re Range	T <sub>stg</sub>	−55 to +125	°C

- Note 1. Reverse connection of supply voltage can cause destruction.
- **Note 2.** The input voltage should be allowed to input without damage or destruction. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The normal operation will establish when the both inputs are within the Common Mode Input Voltage Range of electrical characteristics.
- **Note 3.** This specification is the voltage which should be allowed to supply to the output terminal from external without damage or destructive. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The output voltage of normal operation will be the Output Voltage Swing of electrical characteristics.
- Note 4. Thermal derating factor is -5.0 mV / °C when ambient temperature is higher than 55 °C.
- Note 5. Thermal derating factor is -4.4 mV / °C when ambient temperature is higher than 25 °C.
- **Note 6.** Pay careful attention to the total power dissipation not to exceed the absolute maximum ratings, Note 4 and Note 5.

#### RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V <sup>±</sup>	±4		±16	٧
Output Current	lo			±10	mA
Source Resistance	Rs			50	kΩ
Capacitive Load (A <sub>v</sub> = +1)	CL			100	pF

#### ELECTRICAL CHARACTERISTICS ( $T_a = 25$ °C, $V^{\pm} = \pm 15$ V)

	CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
	Input Offset Voltage	Vıo		±0.3	±5	mV	Rs ≦ 50 Ω
*	Input Offset Current (Note7)	lto		±10	±100	nA	
*	Input Bias Current (Note7)	ĺв		100	400	nA	
	Large Signal Voltage Gain	Αυ	30	300		V/mV	R <sub>L</sub> ≧ 2 kΩ, Vo = ±10 V
	Supply Current	Icc		5	8	mA	lo = 0 A, Both Amplifiers
	Common Mode Rejection Ratio	CMR	80	100		dB	
	Supply Voltage Rejection Ratio	SVR	80	100		dB	
m	Output Voltage Swing	Vom	±12	±13.4		V	R <sub>L</sub> ≧ 10 kΩ
	Output Voltage Swing	Vom	±10	±12.8		V	R <sub>L</sub> ≧ 2 kΩ
	Common Mode Input Voltage Range	Vıсм	±12	±14		V	
	Slew Rate	SR	5	7		V/μs	R <sub>L</sub> ≧ 2 kΩ
	Gain Bandwidth Product	GBW	10	15		MHz	fo = kHz
	Unity Gain Frequency	funity		7		MHz	open loop
	Phase Margin	<b>Ø</b> unity		50		degree	open loop
	Total Harmonic Distortion	THD		0.002		%	Vo = 3 Vr.m.s., f = 20 Hz to 20 kHz (Fig. 1)
*	Input Equivalent Noise Voltage	Vn		0.9		μVr.m.s.	RIAA (Fig. 2)
	Input Equivalent Noise Voltage	Vn		0.53	0.65	μVr.m.s.	FLAT + JIS A, Rs = 100 Ω (Fig. 3)
	Input Equivalent Noise Voltage Density	e <sub>n</sub>		5.5		nV/√Hz	fo = 10 Hz, Rs = 100 Ω
	Input Equivalent Noise Voltage Density	e <sub>n</sub>		4.5		nV/√Hz	fo = 1 kHz, Rs = 100 Ω
	Input Equivalent Noise Voltage Density	İn		0.7		pA/√Hz	fo = 1 kHz
	Channel Separation			120		dB	f = 20 Hz to 20 kHz

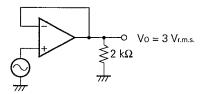
Note 7. Input bias currents flow out from IC. Because each currents are base current of PNP-transistor on input stage.

**Note 8.** For asterisk items, those spec was applied to the production lots mode after Jun. '87 by the effect of input PNP Tr's h<sub>fe</sub> rise. Before spec is following.

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Input Offset Current (Note7)	lio		±10	±200	nA	
Input Bias Current (Note7)	lв		500	1000	nA	
Input Equivalent Noise Voltage	Vn		1.2		μVr.m.s.	RIAA (Fig. 2)

#### **MEASUREMENT CIRCUIT**

Fig. 1 Total Harmonic Distortion Measurement Circuit



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#### Fig. 2 Noise Measurement Circuit (RIAA)

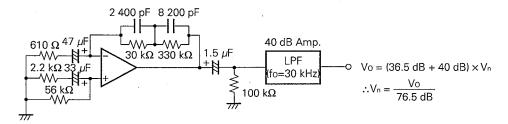
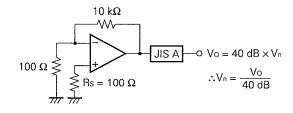
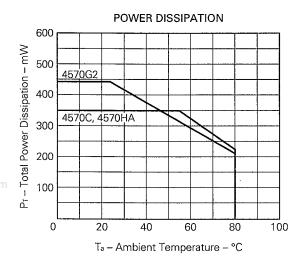
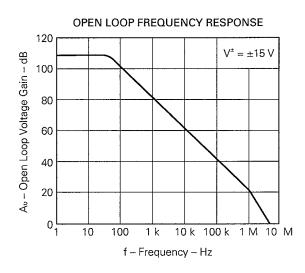


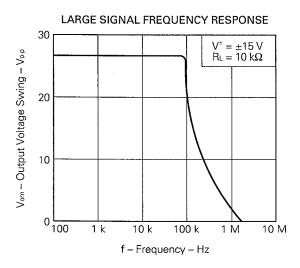
Fig. 3 Noise Measurement Circuit (FLAT + JIS A)

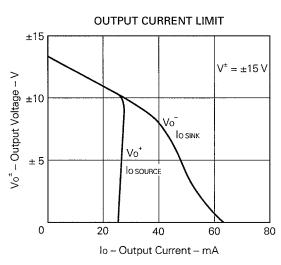


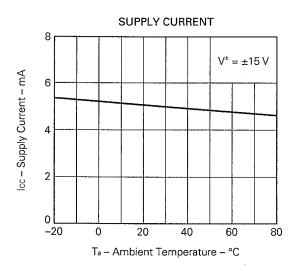
#### TYPICAL PERFORMANCE CHARACTERISTICS (Ta = 25 °C, TYP.)

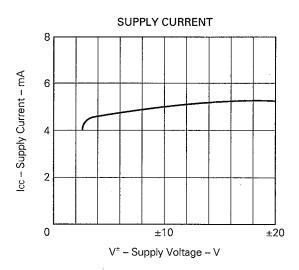


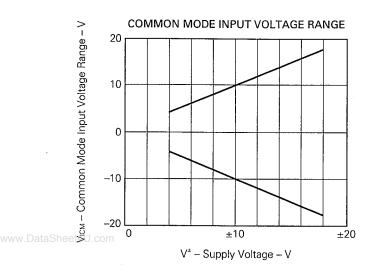


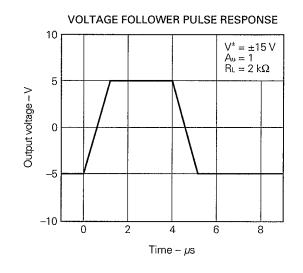


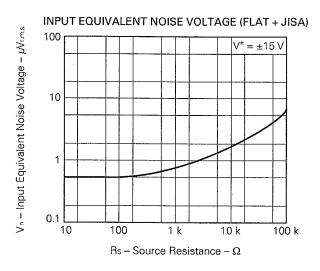


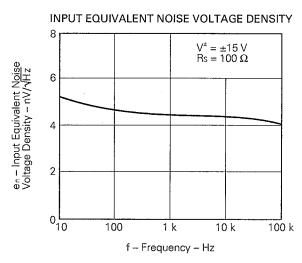


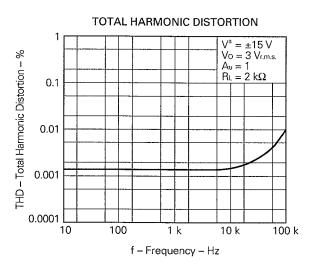




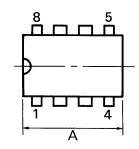


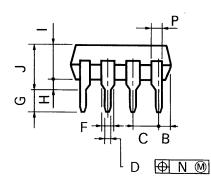


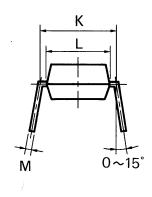




### 8PIN PLASTIC DIP (300 mil)







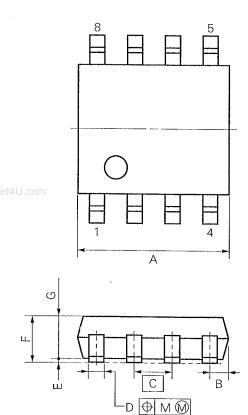
P8C-100-300B,C

#### **NOTES**

- Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
Α	10.16 MAX.	0.400 MAX.
В	1.27 MAX.	0.050 MAX.
С	2.54 (T.P.)	0.100 (T.P.)
D	0.50 <sup>±0.10</sup>	0.020 +0.004
F	1.4 MIN.	0.055 MIN.
G	3.2 <sup>±0.3</sup>	0.126 <sup>±0.012</sup>
Н	0.51 MIN.	. 0.020 MIN.
ı	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
K	7.62 (T.P.)	0.300 (T.P.)
L	6.4	0.252
М	0.25 + 0.10	0.010 -0.003
2	0.25	0.01
Р	0.9 MIN.	0.035 MIN.

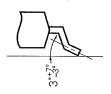
#### 8 PIN PLASTIC SOP (225 mil)

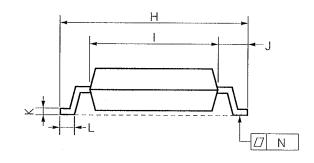


#### NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.



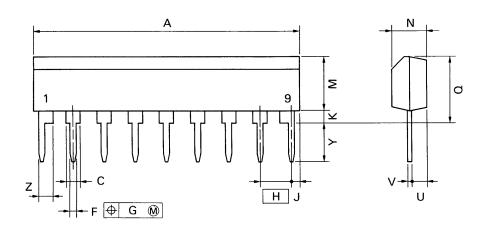




#### S8GM-50-225B-2

[		000W 00 220B 2
ITEM	MILLIMETERS	INCHES
Α	5.37 MAX.	0.212 MAX.
В	0.78 MAX.	0.031 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	$0.40^{+0.10}_{-0.05}$	0.016+0.004
Е	0.1±0.1	0.004±0.004
F	1.8 MAX.	0.071MAX.
G	1.49	0.059
Н	6.5±0.3	0.256±0.012
ı	4.4	0.173
J	1.1	0.043
K	0.15 <sup>+0.10</sup> <sub>-0.05</sub>	0.006+0.004
L	0.6±0.2	0.024+0.008
М	0.12	0.005
N	0.15	0.006

#### **9 PIN PLASTIC SLIM SIP**



NOTE

Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.

P9HA-254B

ITEM	MILLIMETERS	INCHES
Α	22.86 MAX.	0.9 MAX.
С	1.1 MIN.	0.043 MIN.
F	0.5 <sup>±0.1</sup>	0.02+0.004
G	0.25	0.01
н	2.54	0.1
J	1.27 MAX.	0.05 MAX.
К	0.51 MIN.	0.02 MIN.
М	5.08 MAX.	0.2 MAX.
N	2.8 <sup>±0.2</sup>	0.11-0.008
Q	5.75 MAX.	0.227 MAX.
U	1.5 MAX.	0.059 MAX.
V.	0.25 <sup>±8:8</sup>	0.01 -0.003
Y	3.2 <sup>±0.5</sup>	0.126 <sup>±0,02</sup>
Z	1.1 MIN.	0.043 MIN.



#### RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

#### TYPES OF SURFACE MOUNT DEVICE

For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (IEI–1207).

[*μ*PC4570G2]

Soldering method	Soldering conditions	Recommended condition symbol
Infrared ray reflow	Peak package's surface temperature: 230 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 1, Exposure limit*: None	IR30-00-1
VPS	Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 1, Exposure limit*: None	VP15-00-1
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below Number of flow process: 1, Exposure limit*: None	WS15-00-1
Partial heating method	Terminal temperature: 300 °C or below, Flow time: 10 seconds or below, Exposure limit*: None	

<sup>\*:</sup> Exposure limit before soldering after dry-pack package is opened. Storage conditions: 25 °C and relative humidity at 65 % or less.

Note: Do not apply more than a single process at once, except for "Partial heating method."

#### TYPES OF THROUGH HOLE DEVICE

[ $\mu$ PC4570C,  $\mu$ PC4570HA]

Soldering method	Soldering conditions	Recommended condition symbol
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below	

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Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment,

Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.

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